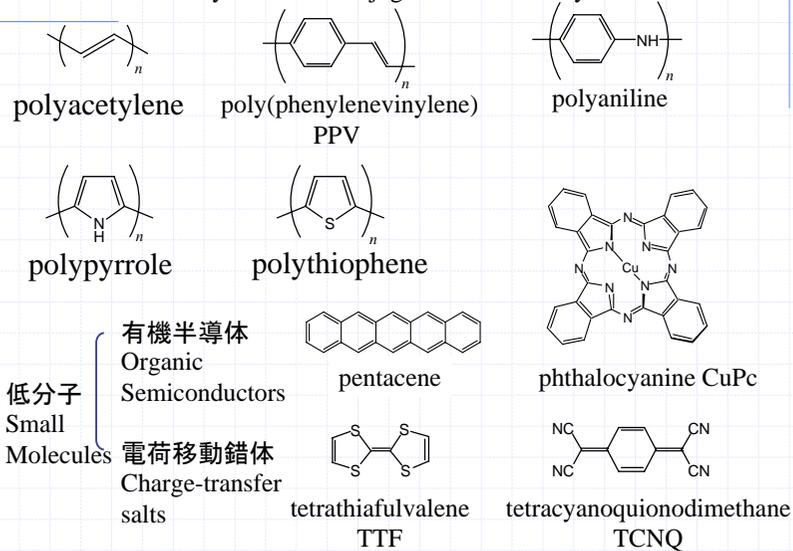
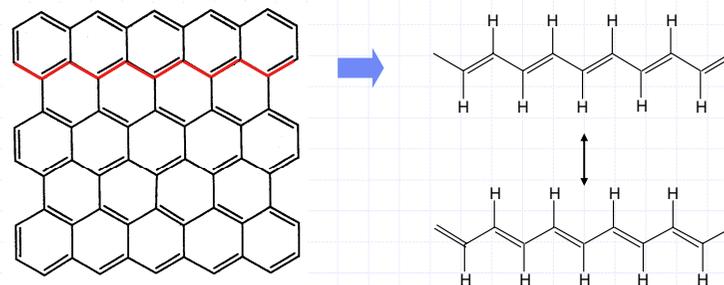


# 有機伝導体 Organic Conductors

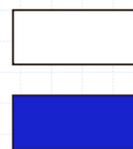
導伝性高分子: Polymers with conjugated  $\pi$ -electron systems



One chain truncated from graphite (terminated by hydrogens)  
→ Polyacetylene

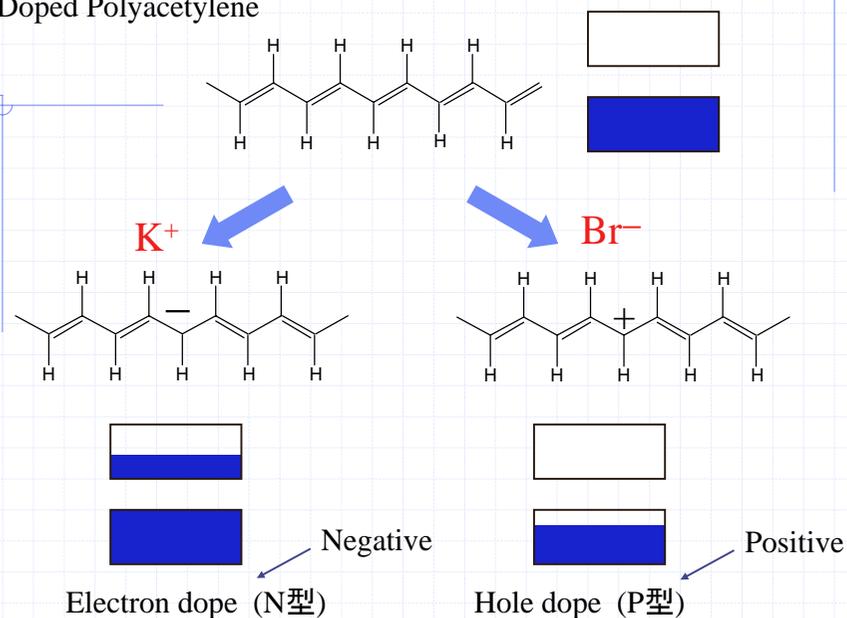


Electrically conducting because the p-electrons can move.

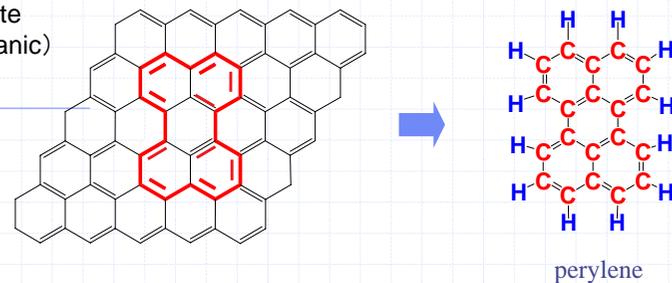


半導体  
Semiconductor 白川英樹 2000年 Nobel Prize  
H. Shirakawa

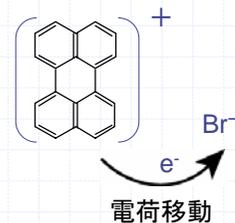
# Doped Polyacetylene



Graphite (Inorganic)



First Electrically Conducting Organics



Br doped Perylene shows as high electric conductivity as  $0.1 \text{ Scm}^{-1}$ .  
First conducting charge-transfer salt  
Akamatsu, Inokuchi, Matsunaga,  
*Nature*, **173**, 168 (1954).

電荷移動 → Charge-transfer complex 電荷移動錯体

## Charge-transfer complex 電荷移動錯体

Electron donor 電子供与体

Compounds easily oxidized to  $D^0 \rightarrow D^+$   
with high HOMO levels

Electron acceptor 電子受容体

Compounds easily reduced to  $A^0 \rightarrow A^-$   
with low LUMO levels

Completely  $D^0A^0 \rightarrow D^+A^-$ : Ionic charge-transfer complex

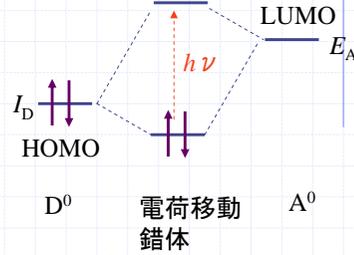
Nearly  $D^0A^0$ : Neutral charge-transfer complex

Small (quantum mechanical) mixing of the ionic state

$$\phi = \phi(D^0A^0) + c\phi(D^+A^-)$$

and the excitation corresponding to  $D^0A^0 \rightarrow D^+A^-$

gives rise to charge-transfer absorption 電荷移動吸収 (visible to infrared)



$$h\nu = I_D - E_A - E(D^+A^-) \sim$$

$$E_{\text{redox}}(\text{HOMO}) - E_{\text{redox}}(\text{LUMO})$$

$> 0.1 \text{ V}$   $D^0A^0$  is more stable  
than  $D^+A^-$ : neutral  
 $< 0.1 \text{ V}$   $D^+A^-$  is more stable  
than  $D^0A^0$ : ionic

Redox Potential 酸化還元電位  
(cyclic voltammetry)

vs. SCE = 0.24 V NHE

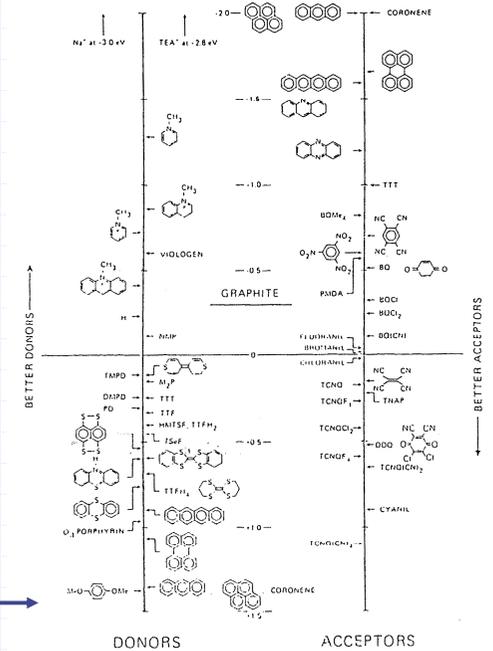
Standard calomel electrode  
vs. Ag/AgCl = 0.22 V NHE

Ferrocene = 0.38 V vs. SCE

Energy level

$$= -E_{\text{redox}}(\text{vs. SCE}) - 4.4 \text{ V}$$

Torrance, *Mol. Cryst. Liq. Cryst.*  
**126**, 55 (1985).



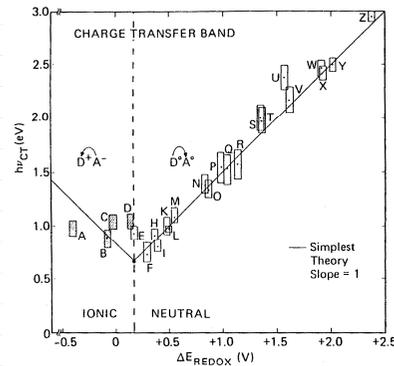
(Mixing solutions of colorless neutral donor and acceptor  
gives an orange to yellow solution.)

$$h\nu = I_D - E_A - E(D^+A^-)$$

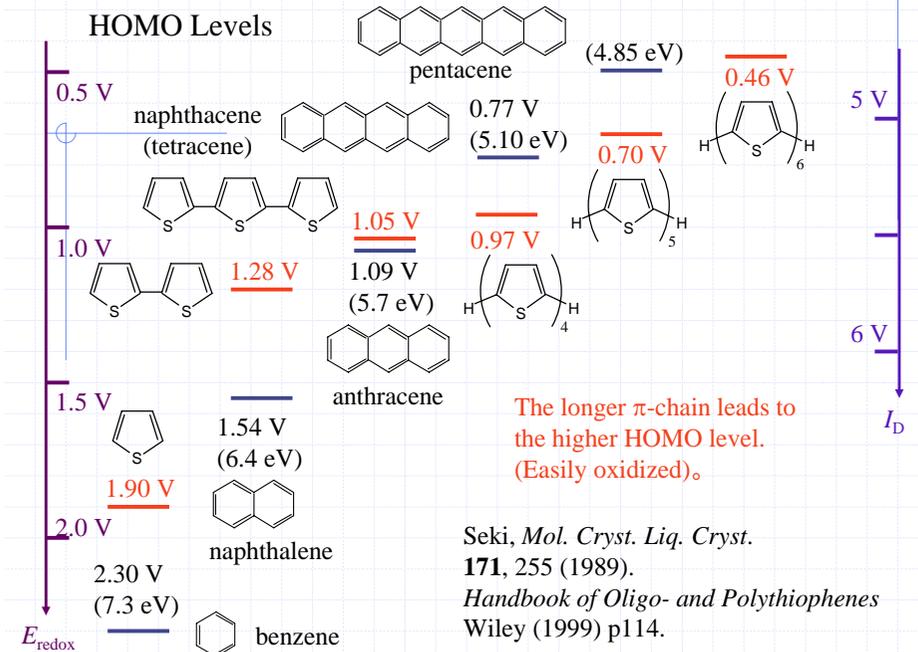
$I_D$ : Ionization energy of the donor  
 $E_A$ : electron affinity of the acceptor  
 $E(D^+A^-)$ : Coulomb attraction of  $D^+$  and  $A^-$   
(Madelung energy)

$$h\nu = I_D - E_A - E(D^+A^-) \sim$$

$$E_{\text{redox}}(\text{HOMO}) - E_{\text{redox}}(\text{LUMO})$$



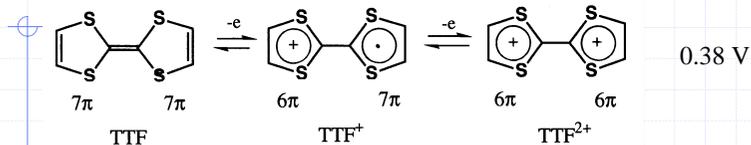
HOMO Levels



## Good donors and acceptors



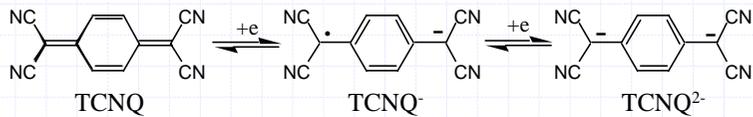
A good donor: Tetrathiafulvalene (TTF)



This  $7\pi$  system easily gives up one electron to form a  $6\pi$  system.  
(C $\rightarrow$ 1 $\pi$ , S $\rightarrow$ 2 $\pi$ )

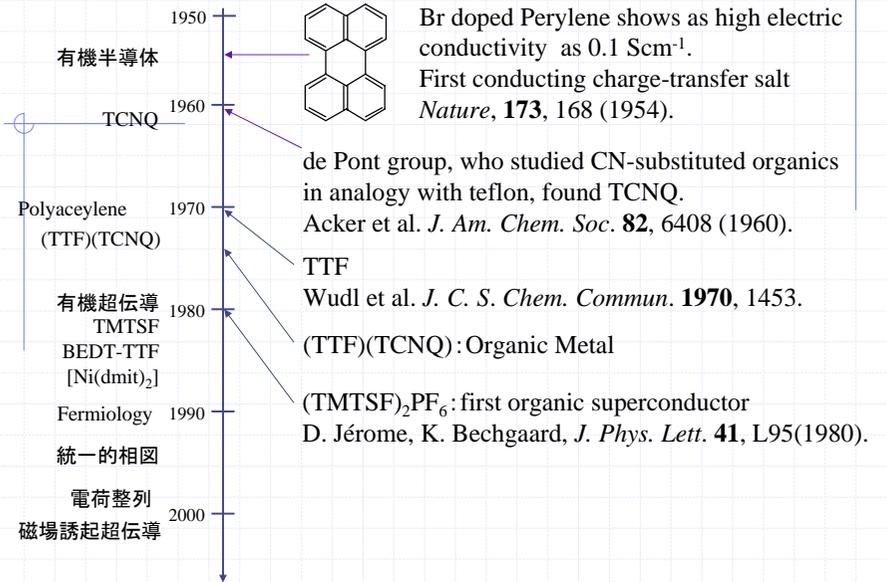
Electron donating groups such as  $-\text{NH}_2$ ,  $-\text{OCH}_3$  strengthen donor ability.

A good acceptor Tetracyanoquinodimethane (TCNQ)



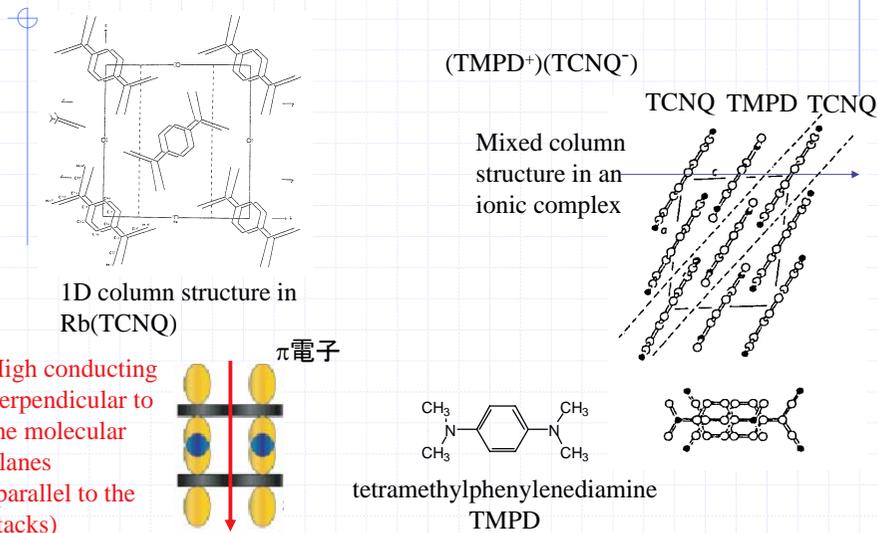
Reduction restores from the quinoid structure to an aromatic  $6\pi$  system.  
- emerges on the foot of two electron withdrawing groups (CN).

Electron withdrawing groups such as  $-\text{CN}$ ,  $-\text{NO}_2$  strengthen acceptor ability.



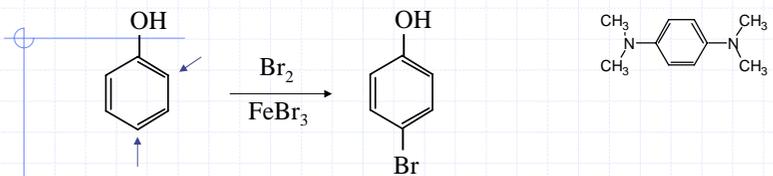
## TCNQ complexes: stable CT complexes

CT complexes like  $\text{M}(\text{TCNQ})$  [M = Li, Na, K, Cu, Ag] with conductivity  $10^{-2} \sim 10^4 \text{ Scm}^{-1}$  (semiconductor due to the 1:1 composition)



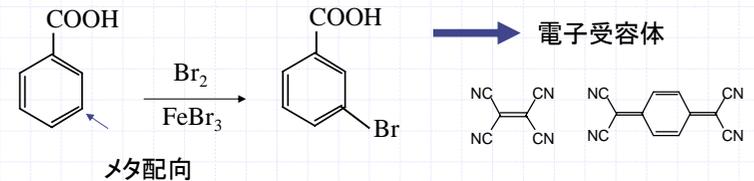
電子供与基:  $-\text{OH}$ ,  $-\text{OCH}_3$ ,  $-\text{NH}_2$

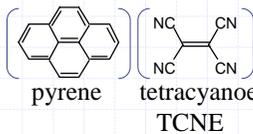
電子供与体



電子吸引基:  $-\text{NO}_2$ ,  $-\text{CN}$ , ハロゲン,  $-\text{COOH}$ ,  $-\text{COOCH}_3$ ,  $-\text{CHO}$

電子受容体

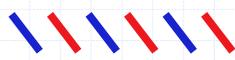




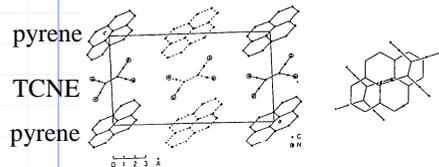
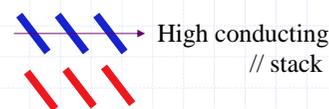
TCNE

Mixed stack in a neutral complex

Mixed stack structure  
Neutral and ionic: low conducting



Segregate stack structure  
Partial charge transfer: high conducting



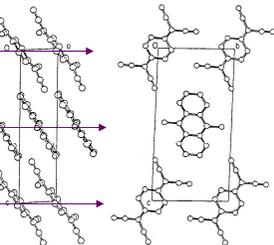
(NMP)(TCNQ): first 「Organic Metal」1966



TCNQ column

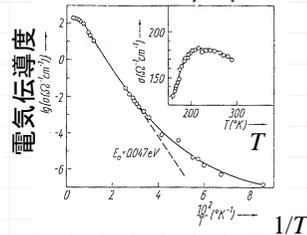
NMP column

TCNQ column



Segregated

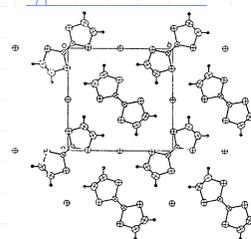
Metal at 200 K ~ rt



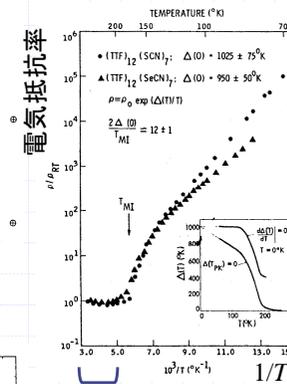
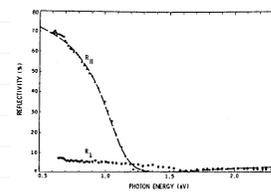
(TTF) $X_x$ : Typical 1D Metal (X=Cl, Br, I, SCN,  $x \sim 0.71$ )

Peierls transition  $\leftarrow$  non magnetic insulator below 200 K

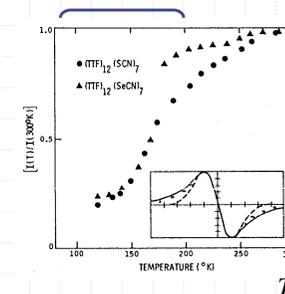
1D stacks



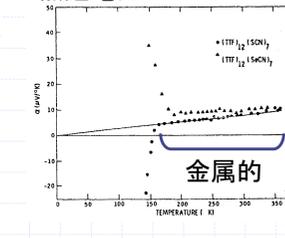
反射率: Strongly 1D



Metallic above 200 K



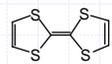
熱起電力



(TTF)(TCNQ)

1973

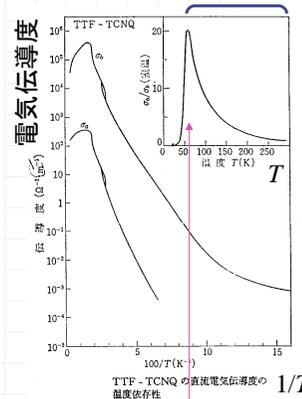
(TTF $^{0.59+}$ )(TCNQ $^{0.59-}$ )



TTF



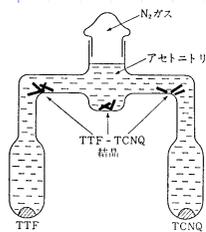
Metal at 54 K ~ rt



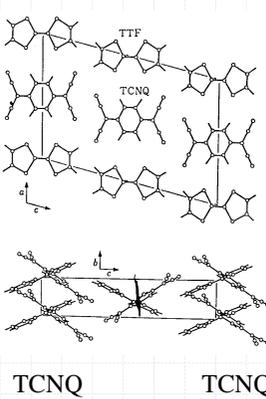
Metal-insulator transition at 54 K

拡散法結晶成長

From acetonitril solutions of TTF and TCNQ

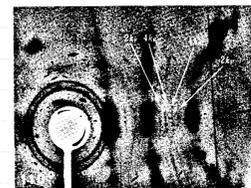
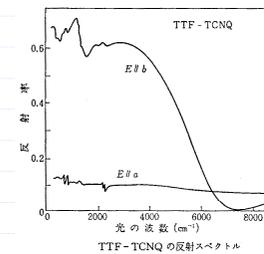


分離積層型



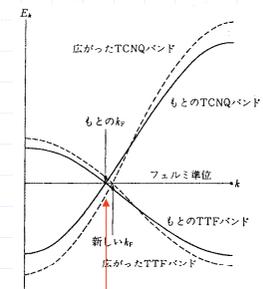
(TTF)(TCNQ)

反射率 一次元金属

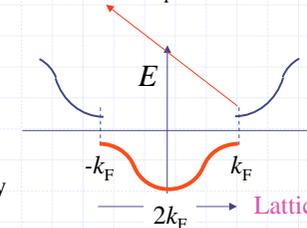


X線:  $2k_F$  periodicity

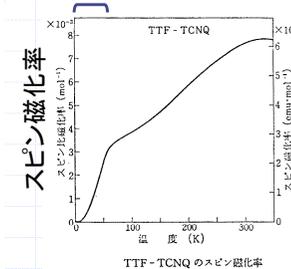
Energy band



HOMO band of TTF and LUMO band of TCNQ cross each other at  $k_F = 0.1475b^* = 0.295\pi/b = (0.59/2)(\pi/b)$

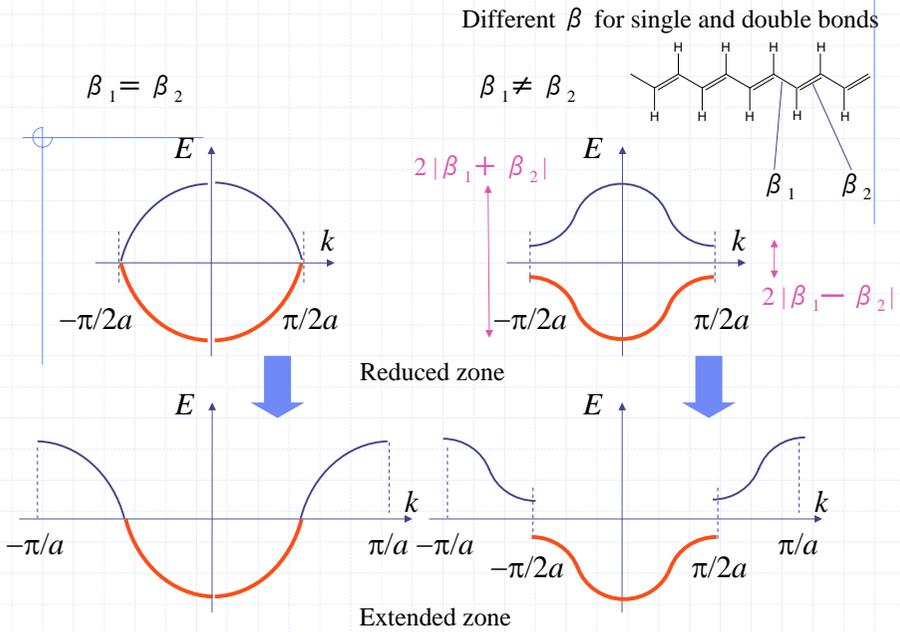


Non magnetic below 54 K

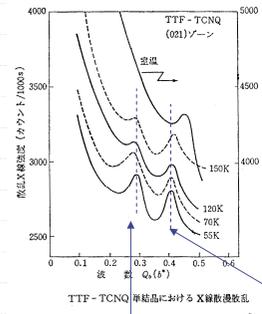


非磁性絶縁体 (Peierls転移)

Lattice has periodicity  $2k_F$

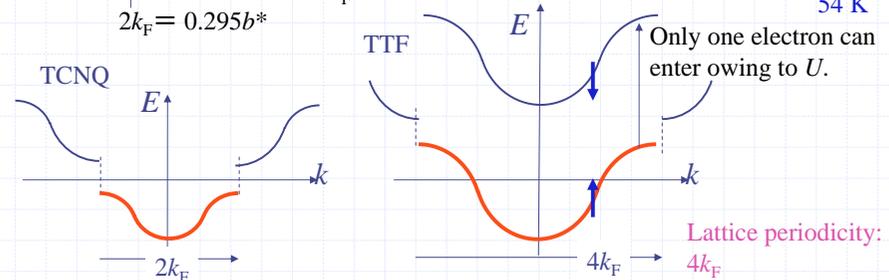
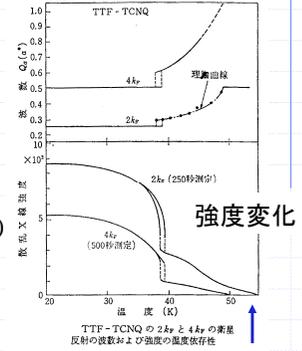


(TTF)(TCNQ)



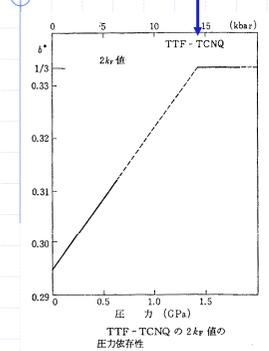
Charge has periodicity with wavelength  $1/2k_F$   
(電荷密度波)  
Charge density wave (CDW)

$k_F$ : 若干温度変化

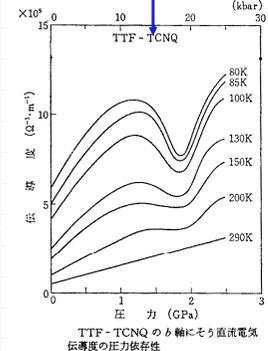


(TTF)(TCNQ)

$2k_F$  changes under pressure.  
"lock in" to  $1/3$  above 15 kbar.

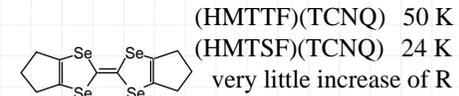
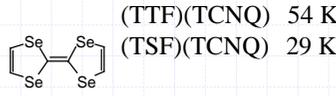


LT conductance decreases above 15 kbar.

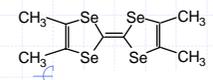


Collective motion of CDW carries current.  
(CDW 集団運動)  
(Frölich mode)

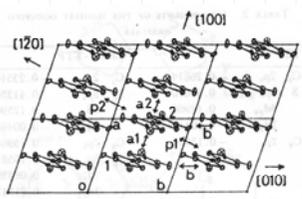
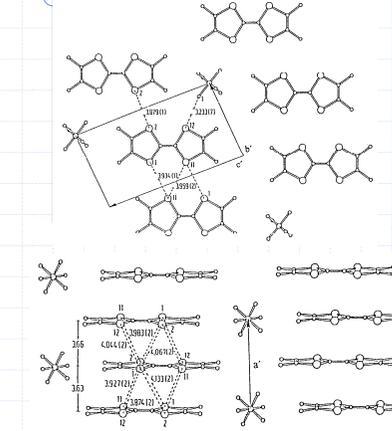
Attempts to reduce the Peierls transition: enhance interchain interaction by Se



(TMTSF)<sub>2</sub>PF<sub>6</sub>: First Organic Superconductor



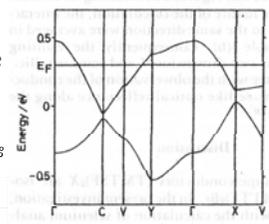
Quasi-1D Metal: Fermi surface is open, but the interchain interaction is 1/10 of the intrachain ones.



Transfer integrals (meV)

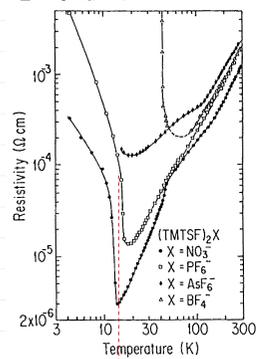
方向	HOMO
a1	200
a2	230
b	35
p1	20
p2	7

計算値 from 分子軌道計算



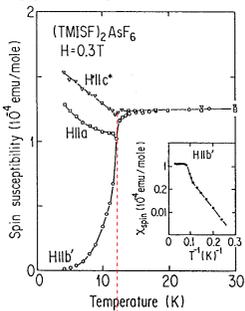
# (TMTSF)<sub>2</sub>PF<sub>6</sub>: First Organic Superconductor

電気抵抗率



金属-半導体転移:  
12 K

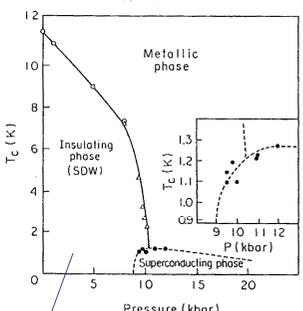
静磁化率



静磁化率異方性:  
12 K以下

反強磁性  
(spin密度波)  
Spin density wave  
(SDW)

压力下相图



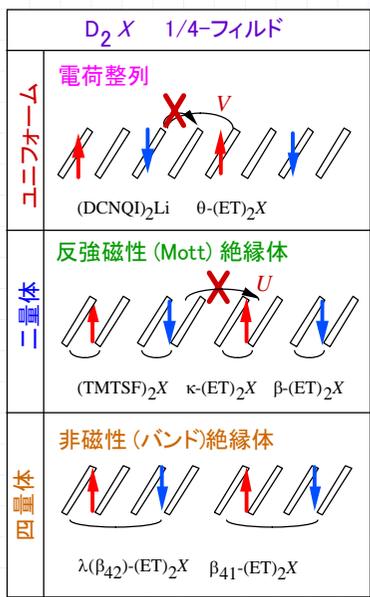
超伝導  $T_c \sim 1$  K

反強磁性(SDW)絶縁相

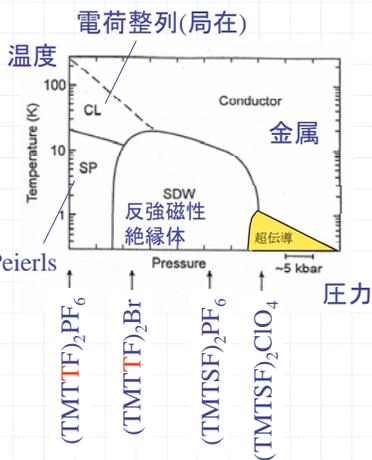


## Experimentally distinguish origins of metal-insulator transitions

	電気抵抗率	静磁化率 (SQUID)	スピン磁化率 (ESR)	X線散乱
電荷密度波(CDW) (Peierls 転移)		$\chi$ 非磁性絶縁体	$\chi_s$ the same 連続線幅 at $T_{MI}$	$2k_F$ 長周期 $> T_{MI}$ 散漫散乱 $< T_{MI}$ spots
Spin 密度波 (SDW)		反強磁性絶縁体	線幅発散	non
Mott 絶縁体・電荷整列		常磁性絶縁体	The same $\chi_s$ 線幅連続 at $T_{MI}$	Mott: non 電荷整列: 長周期
Spin-Peierls 転移		$\chi$ 非磁性絶縁体	The same $\chi_s$ 線幅連続 at $T_{MI}$ The same as CDW singlet-triplet model	$2k_F$ の長周期



(TMTSF)<sub>2</sub>X (擬一次元) 系 統一的相图(Jérome相图)

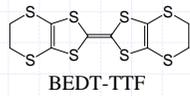


Timeline of organic superconductors:

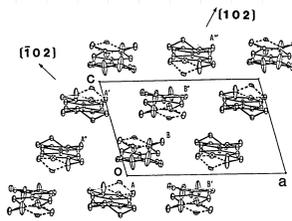
- 1950: 有機半導体
- 1960: TCNQ
- 1970: Polyacetylene (TTF)(TCNQ)
- 1980: 有機超伝導 TMTSF, BEDT-TTF, [Ni(dmit)<sub>2</sub>]
- 1980: (TMTSF)<sub>2</sub>PF<sub>6</sub>: 最初の有機超伝導  $T_c=1.4$  K (6.5 kbar) D. Jérôme, K. Bechgaard 1980
- 1981: (TMTSF)<sub>2</sub>ClO<sub>4</sub>: 常圧有機超伝導体  $T_c=1.4$  K 1981
- 1983: (BEDT-TTF)<sub>2</sub>ClO<sub>4</sub>(TCE): 2次元有機伝導体 G. Saito, T. Enoki, H. Kobayashi
- 1983: (BEDT-TTF)<sub>2</sub>ReO<sub>4</sub>  $T_c=2$  K (4 kbar) 1983
- 1984:  $\beta$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>  $T_c=1.5$  K  $\rightarrow T_c=8$  K (1.2 kbar) Yagubskii 1984 Murata, Laukhin 1985
- 1987:  $\kappa$ -(BEDT-TTF)<sub>2</sub>Cu(NCS)<sub>3</sub>  $T_c=10.4$  K H. Urayama, G. Saito 1987
- 1990: Fermiology
- 1990: 統一的相图
- 1990:  $\kappa$ -(BEDT-TTF)<sub>2</sub>Cu[N(CN)<sub>2</sub>]Br  $T_c=11.6$  K
- 1990:  $\kappa$ -(BEDT-TTF)<sub>2</sub>Cu[N(CN)<sub>2</sub>]Cl  $T_c=12.8$  K (0.3 kbar) J. M. Williams 1990
- 2000: 電荷整列
- 2001:  $\lambda$ -(BETS)<sub>2</sub>FeCl<sub>4</sub>: 磁場誘起超伝導 Uji 2001
- 2003:  $\beta'$ -(BEDT-TTF)<sub>2</sub>ICl<sub>2</sub>  $T_c=14$  K (82 kbar) Taniguchi, 2003

(BEDT-TTF)<sub>2</sub>ClO<sub>4</sub>(TCE) TCE: 1,1,2-trichloroethane  
 G. Saito, T. Enoki, *Solid State Commun.* **42**, 557 (1982).  
 H. Kobayashi, et al. *J. Am. Chem. Soc.* **105**, 297 (1983).

最初の2次元有機伝導体: 金属的電気伝導性@低温



β 構造  
 no conductivity  
 anisotropy

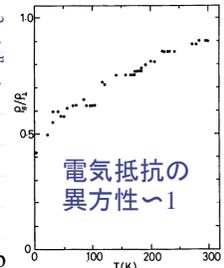
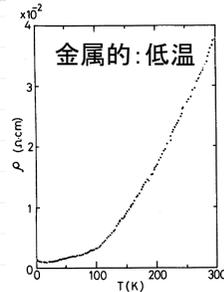


(BEDT-TTF)<sub>3</sub>(ClO<sub>4</sub>)<sub>2</sub>(T<sub>M1</sub> = 170 K) is most easily obtained as the ClO<sub>4</sub> salt.



IBM Group *Phys. Rev. Lett.* **50**, 270 (1983)

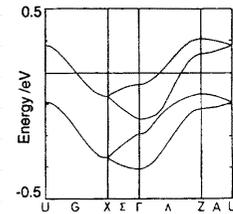
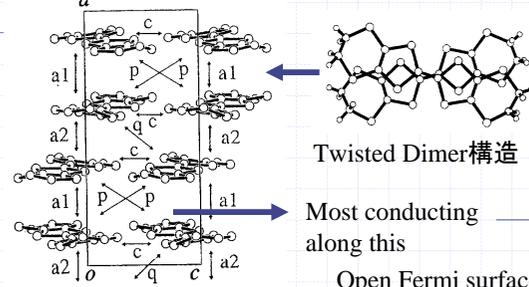
First Organic Superconductor of BEDT-TTF: T<sub>c</sub> = 2 K (4 kb)  
 None can reproduce. ((BEDT-TTF)<sub>3</sub>(ReO<sub>4</sub>)<sub>2</sub> is the majority phase among the ReO<sub>4</sub> salts, so the 2:1 salt is not obtained.)



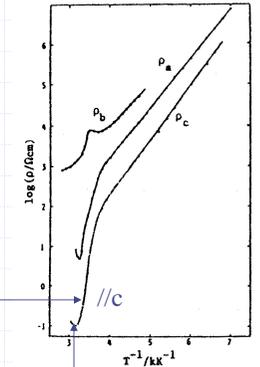
β-(BEDT-TTF)<sub>2</sub>PF<sub>6</sub>: 1D along transverse

H. Kobayashi, *Chem. Lett.* **1983**, 581.

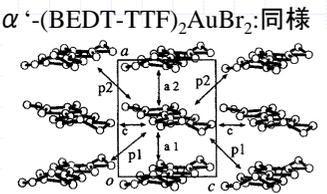
Senadeera, *J. Phys. Soc. Jpn.* **67**, 4193 (1998).



Open Fermi surface //c

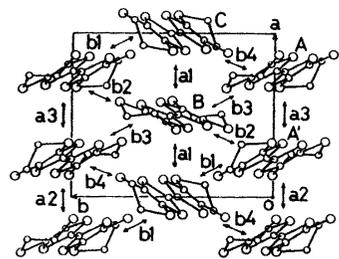


α'-(BEDT-TTF)<sub>2</sub>AuBr<sub>2</sub>: 同様



α-(BEDT-TTF)<sub>2</sub>I<sub>3</sub>

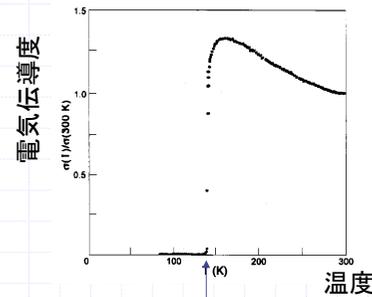
「α相」起源物質



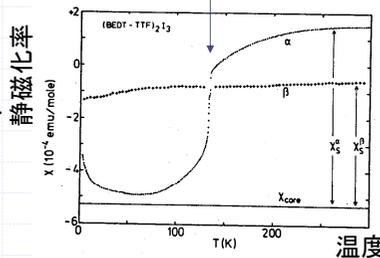
K. Bender, *Mol. Cryst. Liq. Cryst.* **108**, 359 (1984).

T. Mori et al. *Chem. Lett.* **1984**, 957.

Rothamel, *Phys. Rev. B* **34**, 704 (1986).



金属-半導体転移 @ 135 K → 非磁性絶縁体へ。



β-(BEDT-TTF)<sub>2</sub>I<sub>3</sub>

First ambient pressure superconductor based on BEDT-TTF (T<sub>c</sub> = 1.5 K).

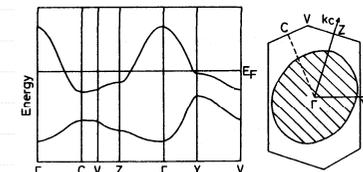
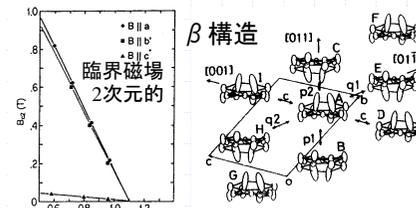
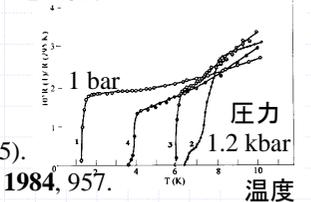
Yagubskii et al. *JETP Lett.* **39**, 12 (1984).

Small pressure increases T<sub>c</sub> to 8 K. Murata *JPSJ*

**54**, 1236 (1985). Laukhin *JETP Lett.* **41**, 81 (1985).

First 2D close Fermi surface: Mori et al. *Chem. Lett.* **1984**, 957.

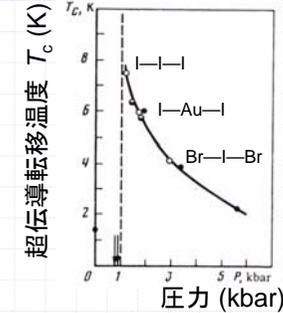
電気抵抗



Linear anions AuI<sub>2</sub>, IBr<sub>2</sub> other than I<sub>3</sub> make β型超伝導体 (I<sub>2</sub>Br: asymmetry → ×)

$$k_B T_c = 1.13 \hbar \omega_D \exp(-1/D(E_F)V)$$

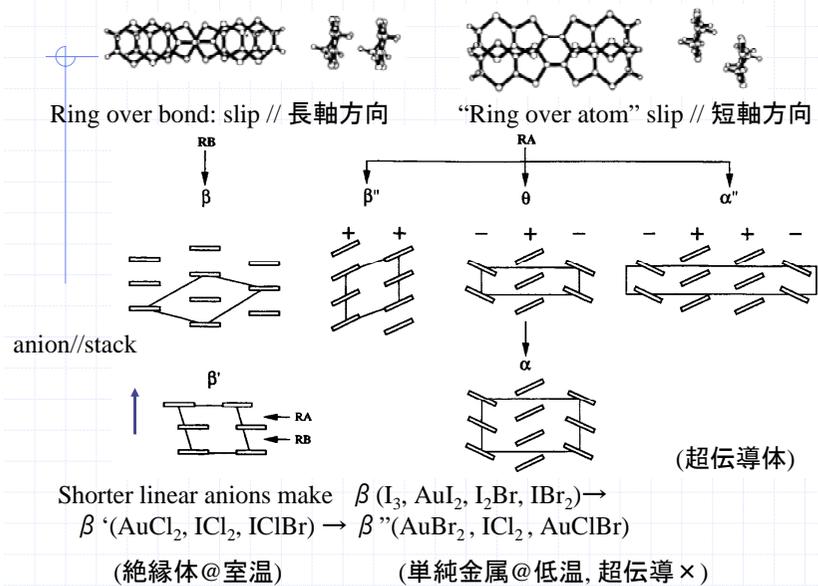
V: 引力



anion 小  
 単位格子大  
 状態密度 D(E<sub>F</sub>) 大  
 転移温度 T<sub>c</sub> 大

## BEDT-TTF塩:構造分類

Mori, *Bull. Chem. Soc. Jpn.* **71**, 2509 (1998); **72**, 179 (1999); **72**, 2011 (1999).

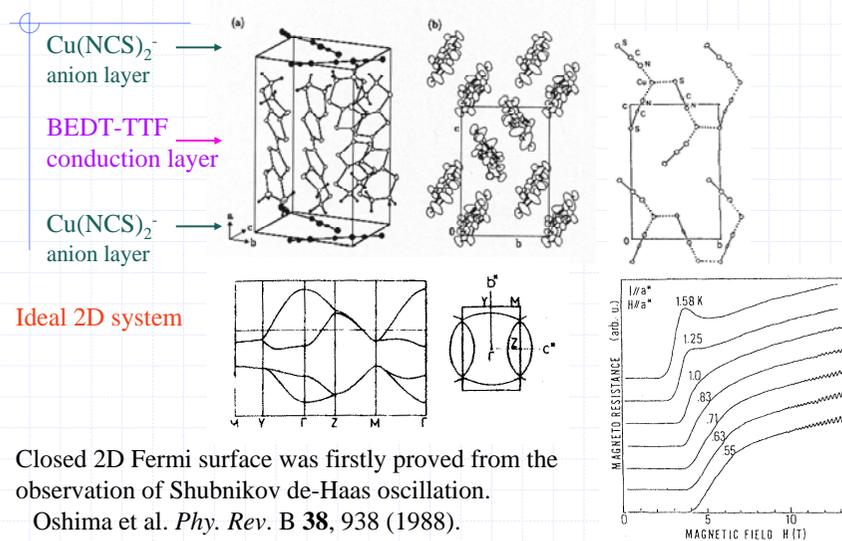


## 電気化学的結晶成長



## $\kappa$ -(BEDT-TTF) $_2$ Cu(NCS) $_2$

First organic superconductor with exceeding  $T_c = 10$  K ( $T_c = 10.4$  K)  
Urayama et al. *Chem. Lett.* **1988**, 55; **1988**, 463.



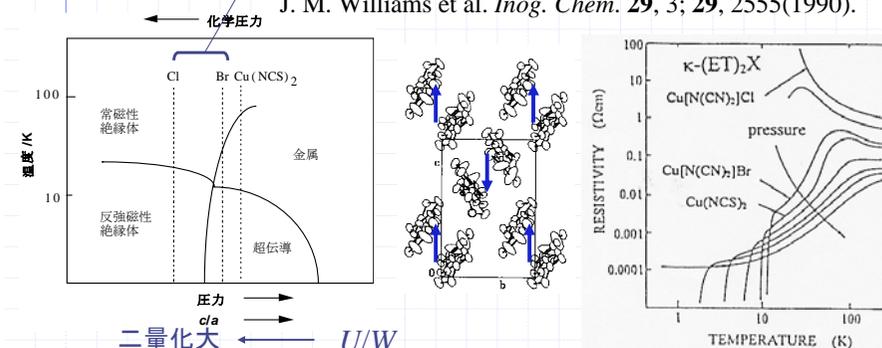
## $\kappa$ 相統一の相図(鹿野田 diagram)

K. Kanoda, *Hyperfine Interact.* **104**, 235 (1997).

$\kappa$ -(BEDT-TTF) $_2$ Cu[N(CN) $_2$ ]Br  $T_c = 11.6$  K

$\kappa$ -(BEDT-TTF) $_2$ Cu[N(CN) $_2$ ]Cl  $T_c = 12.8$  K (0.3 kbar)

J. M. Williams et al. *Inorg. Chem.* **29**, 3; **29**, 2555(1990).

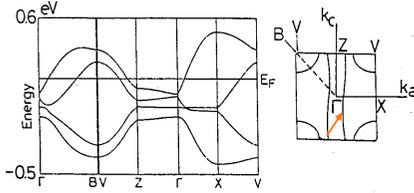
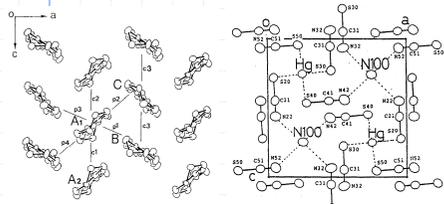


Insulating phase of the  $\kappa$ -phase is a Mott (antiferromagnetic at LT) insulating phase because strong dimerization makes the 1/4-filled band to effectively half filled.  
Superconductivity appears close to the Mott insulating phase similarly to the copper oxides, suggesting Cooper pair formation related to antiferromagnetic correlation.

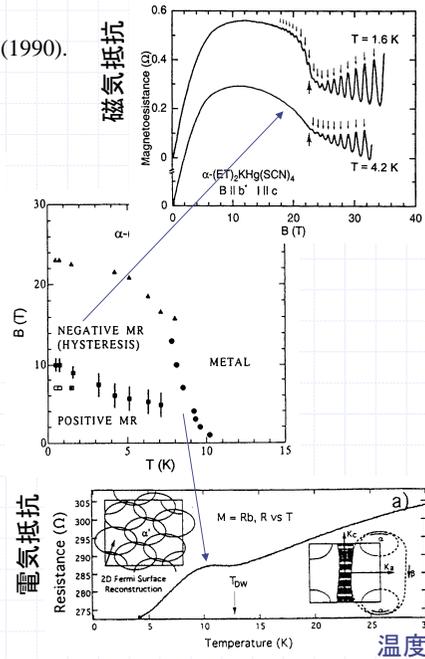
$\alpha$ -(BEDT-TTF)<sub>2</sub>KHg(SCN)<sub>4</sub>

H. Mori, *Bull. Chem. Soc. Jpn.* **63**, 2183 (1990).  
Osada, *Phys. Rev. B* **41**, 5428 (1990).

K → NH<sub>4</sub>: Superconductor at 0.8 K

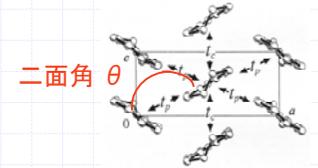


Open Fermi surface makes CDW or SDW at 8 K

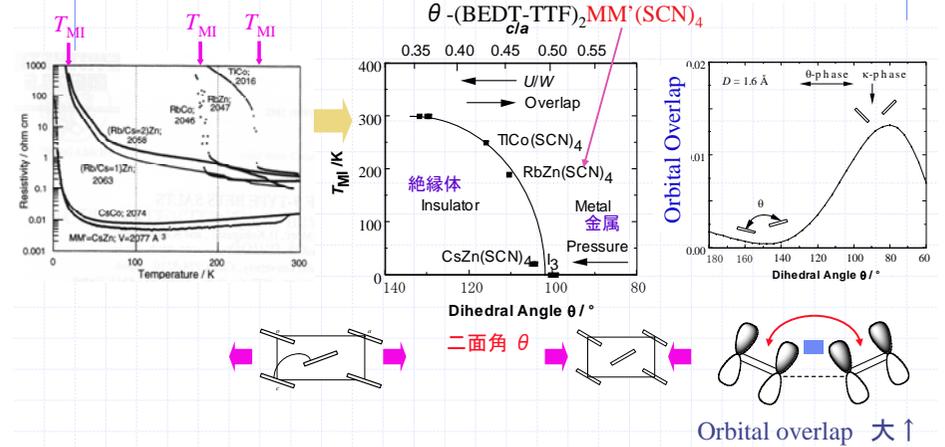


$\theta$  相統一の相図

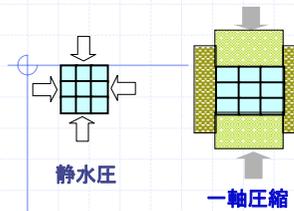
H. Mori et al. *Phys. Rev. B* **57**, 12023 (1998).



$\theta$ -(BEDT-TTF)<sub>2</sub>MM'(SCN)<sub>4</sub>



一軸圧縮法 → 統一の相図検証

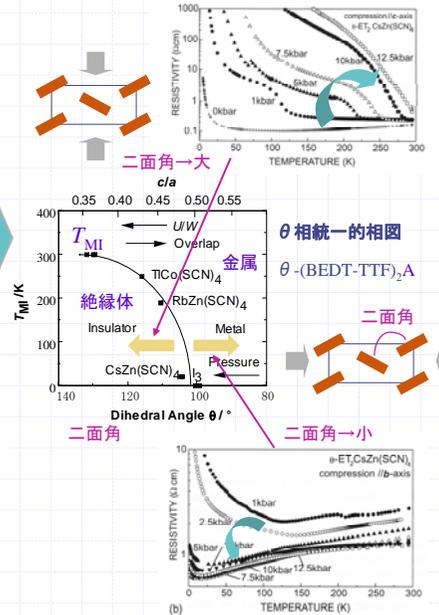


Subtle control different from hydrostatic. Organics are susceptible to pressure.

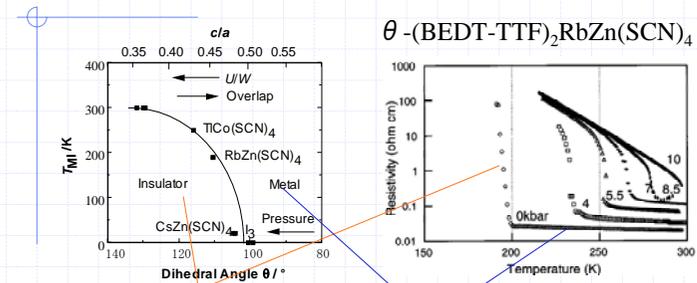
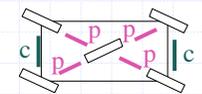
Superconducting only under uniaxial strain

- $\alpha$ -(BEDT-TTF)<sub>2</sub>KHg(SCN)<sub>4</sub>
- $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>
- $\theta$ -(DIETS)<sub>2</sub>Au(CN)<sub>4</sub>

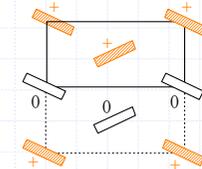
$\theta$ -(BEDT-TTF)<sub>2</sub>CsZn(SCN)<sub>4</sub>



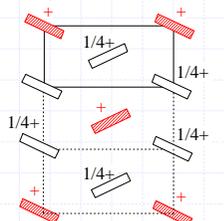
$\theta$  相電荷整理  
 $\theta$  相: uniform 2次元格子  
電荷整理 ← 絶縁化

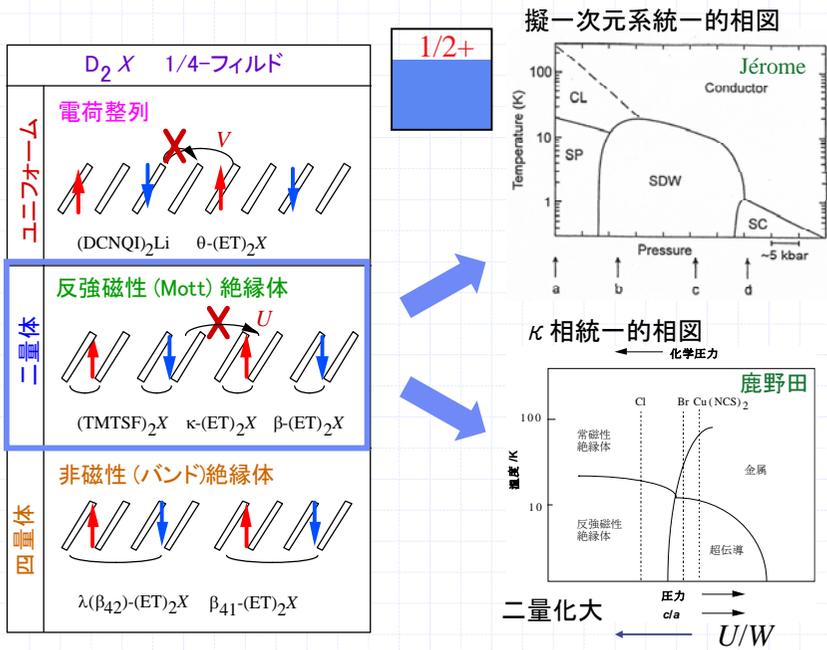


低温絶縁相: 電荷整理  
Horizontal stripe

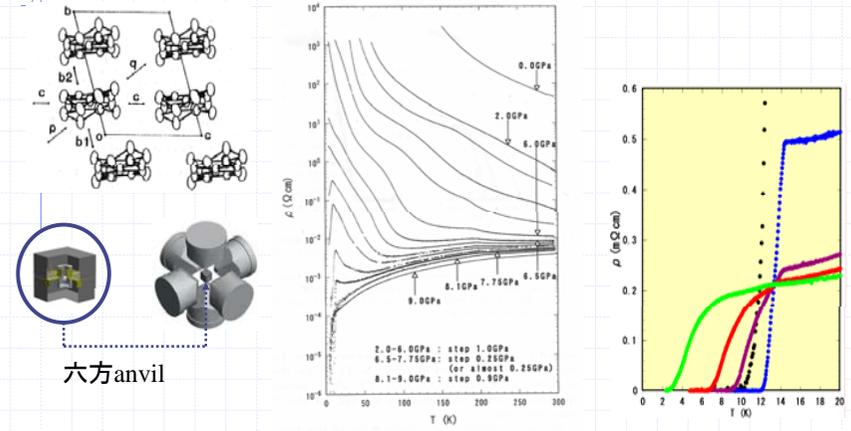


「金属」相: 3倍non-stripe  
電荷整理 → 平坦電気抵抗  
NMR, ラマン, X線  
 $T_{MI}$  1次転移

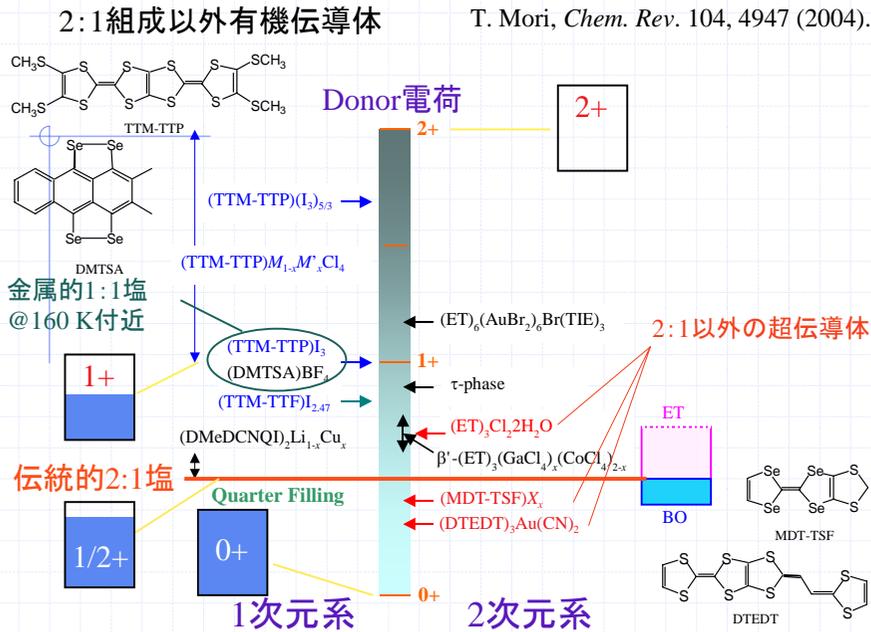




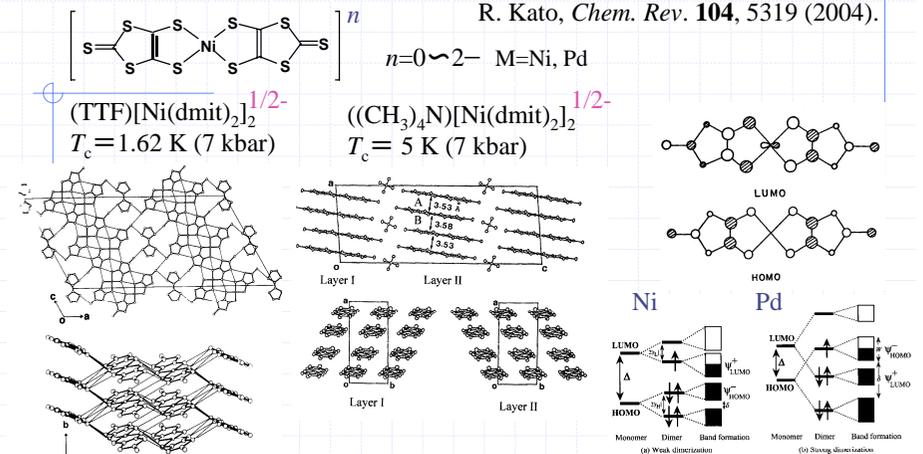
$\beta'$ -(BEDT-TTF)<sub>2</sub>ICl<sub>2</sub>超伝導  $T_c=14.2$  K (82 kbar) @超高压下  
Taniguchi, et al. *J. Phys. Soc. Jpn.*, **72**, 468 (2003).



Apply ultra high pressure to a room-temperature Mott insulator to achieve record high  $T_c$ .



$[M(dmit)_2]$ : Only anionic organic superconductor R. Kato, *Chem. Rev.* **104**, 5319 (2004).

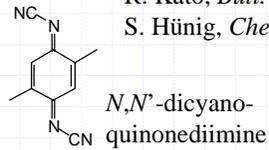
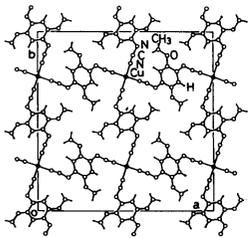


(EDT-TTF)[Ni(dmit)<sub>2</sub>](1.3 K) is ambient, others are high-pressure superconductors. 1D band. HOMO and LUMO have close energy levels, so that the dimerization (particularly in Pd complexes) leads to crossing HOMO and LUMO bands.

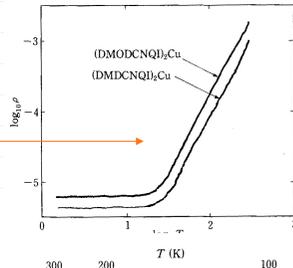
Cu(DMDCNQI)<sub>2</sub> Organic conductor coordinated to metals

R. Kato, *Bull. Chem. Soc. Jpn.* **73**, 515 (2000).  
S. Hünig, *Chem. Rev.* **104**, 5535 (2004).

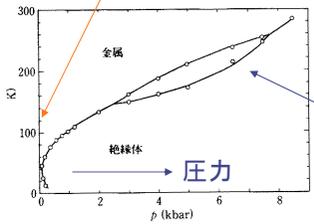
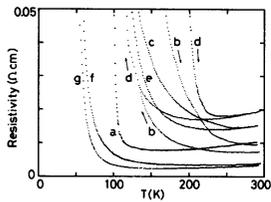
1D stack  
N of CN coordinate to Cu



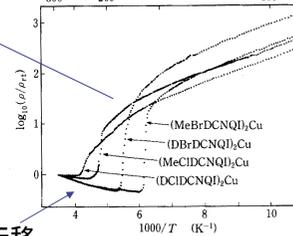
DMDCNQI  
Cu<sup>1.3+</sup> mediates interchain interaction to make metallic @LT



Cu → Li, Na, Ag  
→ Peierls転移

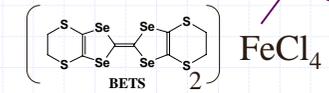


Halogen substituted DCNQI: 金属-半導体転移

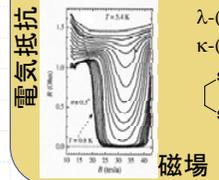


Organic conductors with magnetic anions (π d系)

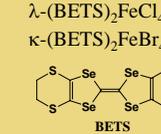
magnetic anion



磁場誘起超伝導

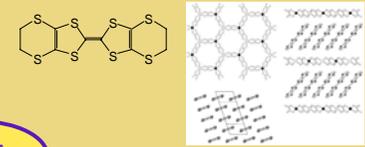


磁場



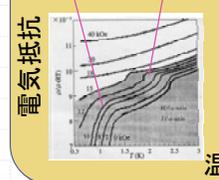
強磁性金属

(BEDT-TTF)<sub>3</sub>[MnCr(C<sub>2</sub>O<sub>4</sub>)<sub>3</sub>]CH<sub>2</sub>Cl<sub>2</sub>

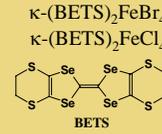


π d系

超伝導と反強磁性の共存

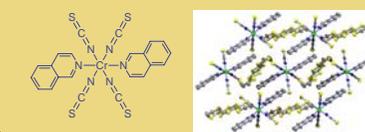


温度



フェリ磁性電荷移動錯体

(Donor) [Cr(NCS)<sub>4</sub>(isoq)<sub>2</sub>]



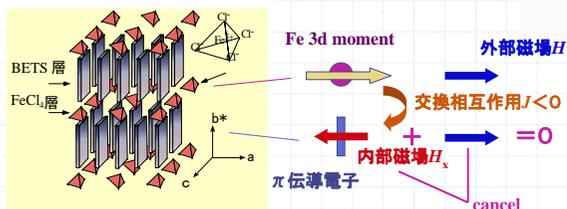
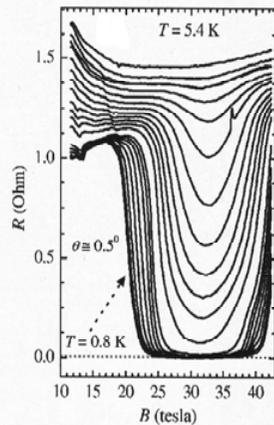
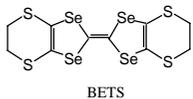
磁場誘起超伝導 λ-(BETS)<sub>2</sub>FeCl<sub>4</sub>

Usually magnetic field destroys superconductivity

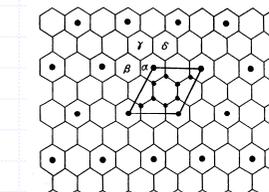
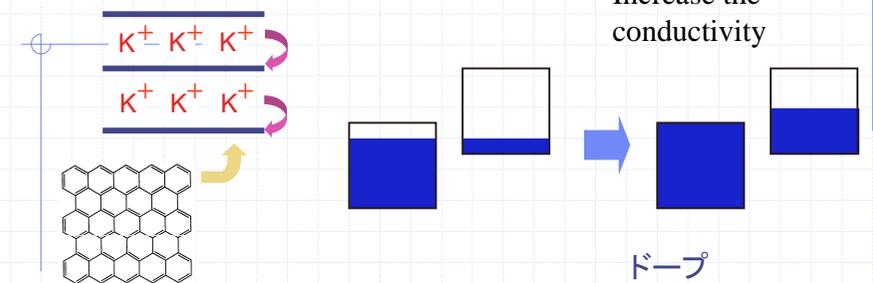
In λ-(BETS)<sub>2</sub>FeCl<sub>4</sub>, superconductivity appears only at magnetic field.

Comig from the π-d interaction

S. Uji, et al *Nature*, **410**, 908(2001).



Graphite 層間化合物



C<sub>8</sub>K

Superconducting at very low T

C<sub>8</sub>K T<sub>c</sub> = 0.39-0.55 K

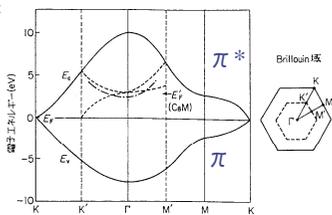
C<sub>8</sub>Rb T<sub>c</sub> = 0.03-0.15 K

C<sub>8</sub>Cs T<sub>c</sub> = 0.02-0.14 K

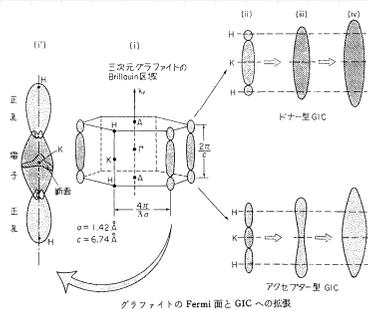
図6 グラファイト・カリウム C<sub>8</sub>K 中のカリウム原子(●印)の配置

# Energy band of graphite

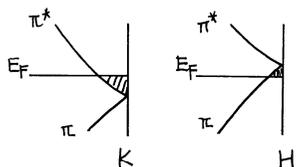
2次元半金属



二次元グラファイトの電子エネルギー帯  
[縦軸、一点鎖線はCaM (Mはアルカリ金属)の場合]

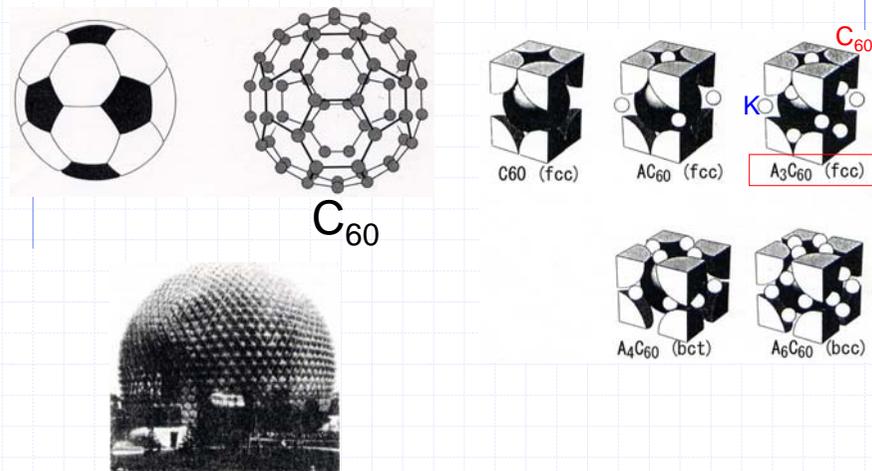


グラファイトの Fermi 面と GIC への挿入



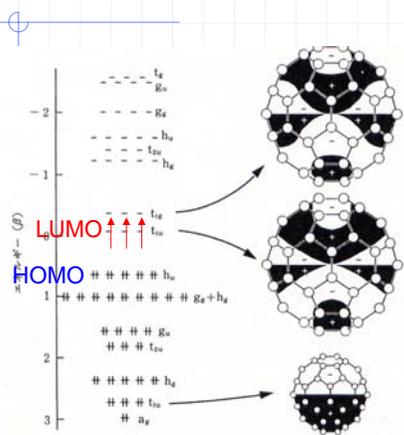
# 3次元の分子性超伝導体: K<sub>3</sub>C<sub>60</sub>

Fullerene



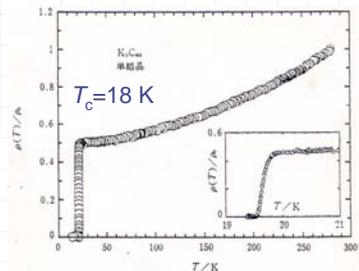
Buckminster Fuller制作Dome

# K<sub>3</sub>C<sub>60</sub>分子軌道&超伝導

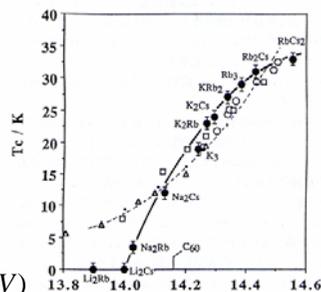


弱結合BCS

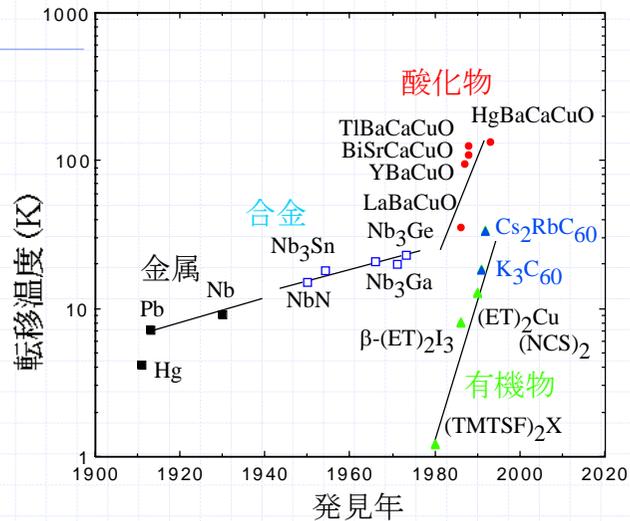
$$k_B T_c = 1.13 \hbar \omega_D \exp(-1/D(E_F)V)$$



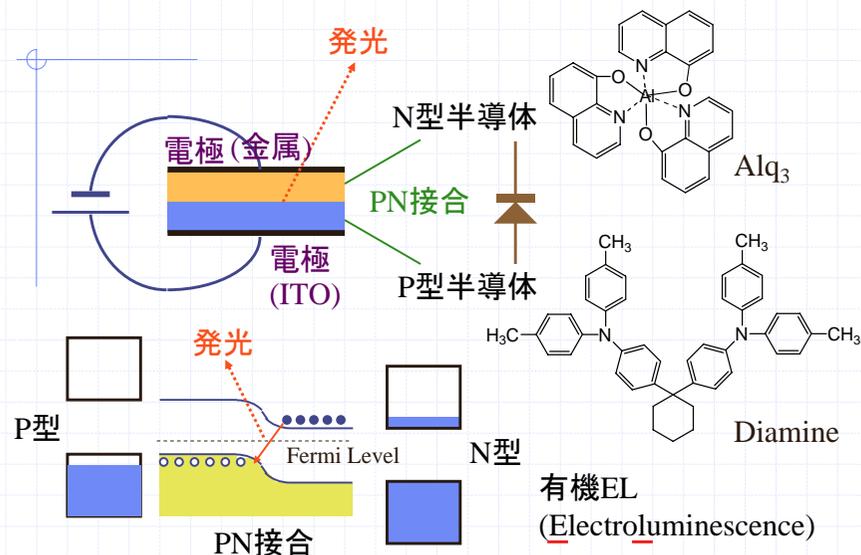
cf. Tc=33K (Cs<sub>2</sub>RbC<sub>60</sub>)



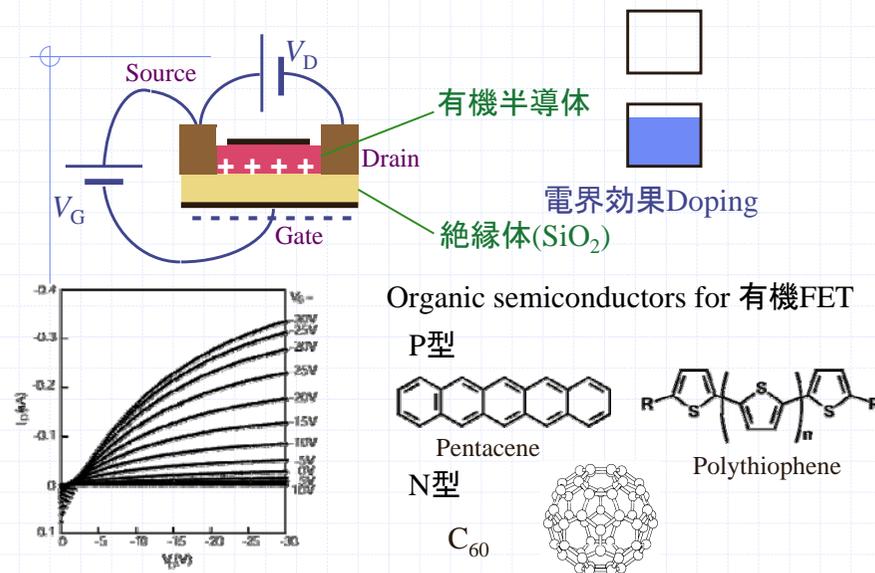
# 超伝導物質の転移温度と発見年



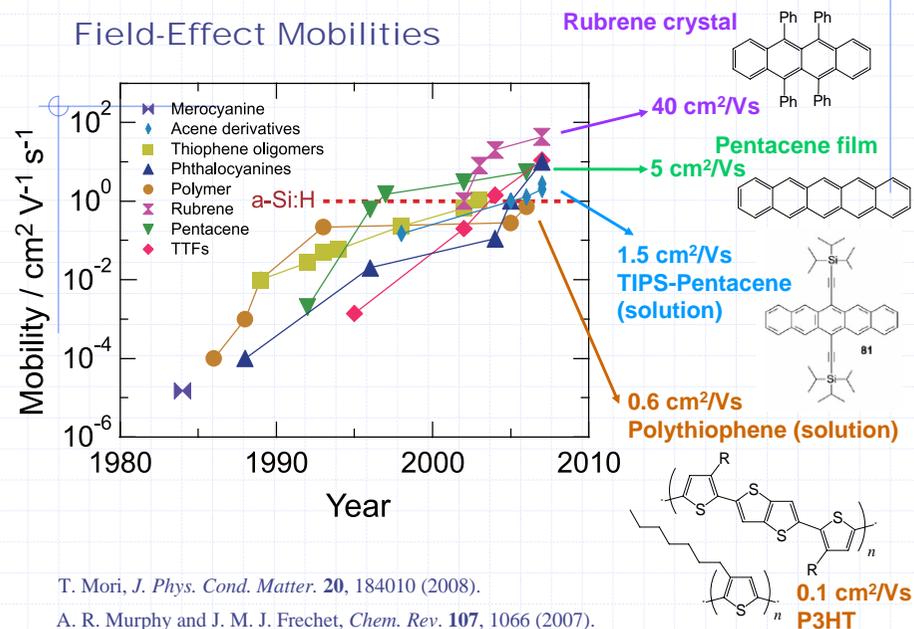
## Organic Light Emitting Diode (LED)



## Organic Field-Effect Transistor (FET)



## Field-Effect Mobilities



T. Mori, *J. Phys. Cond. Matter.* **20**, 184010 (2008).

A. R. Murphy and J. M. J. Frechet, *Chem. Rev.* **107**, 1066 (2007).

## Structures of Organic Semiconductors *Acta Crystallogr. B* **45**, 473 (1989).

